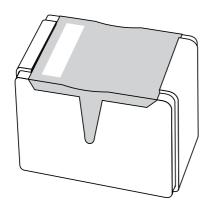
DISCRETE SEMICONDUCTORS

DATA SHEET



BAS216High-speed switching diode

Product specification Supersedes data of 1999 Apr 22 2002 May 28





High-speed switching diode

BAS216

FEATURES

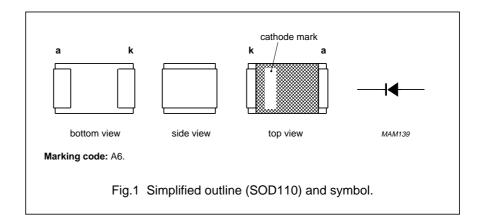
- Small ceramic SMD package
- High switching speed: max. 4 ns
- Continuous reverse voltage: max. 75 V
- Repetitive peak reverse voltage: max. 85 V
- Repetitive peak forward current: max. 500 mA.

APPLICATIONS

 High-speed switching in e.g. surface mounted circuits.

DESCRIPTION

The BAS216 is a high-speed switching diode fabricated in planar technology, and encapsulated in the SOD110 very small rectangular ceramic SMD package.



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|------------------|-------------------------------------|---|------|------|------|
| V _{RRM} | repetitive peak reverse voltage | | _ | 85 | V |
| V _R | continuous reverse voltage | | _ | 75 | V |
| I _F | continuous forward current | note 1 | _ | 250 | mA |
| I _{FRM} | repetitive peak forward current | | _ | 500 | mA |
| I _{FSM} | non-repetitive peak forward current | square wave; T _j = 25 °C prior to surge; see Fig.4 | | | |
| | | t = 1 μs | _ | 4 | Α |
| | | t = 1 ms | _ | 1 | Α |
| | | t = 1 s | _ | 0.5 | Α |
| P _{tot} | total power dissipation | T _{amb} = 25 °C; see Fig.2; note 1 | _ | 400 | mW |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| Tj | junction temperature | | _ | 150 | °C |

Note

1. Device mounted on an FR4 printed-circuit board.

High-speed switching diode

BAS216

ELECTRICAL CHARACTERISTICS

 T_j = 25 °C unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|-----------------|--------------------------|---|------|------|------|
| V _F | forward voltage | see Fig.3 | | | |
| | | I _F = 1 mA | _ | 715 | mV |
| | | I _F = 10 mA | _ | 855 | mV |
| | | I _F = 50 mA | _ | 1 | V |
| | | I _F = 150 mA | _ | 1.25 | V |
| I _R | reverse current | see Fig.5 | | | |
| | | V _R = 25 V | _ | 30 | nA |
| | | V _R = 75 V | _ | 1 | μΑ |
| | | V _R = 25 V; T _j = 150 °C | _ | 30 | μΑ |
| | | V _R = 75 V; T _j = 150 °C | _ | 50 | μΑ |
| C _d | diode capacitance | f = 1 MHz; V _R = 0; see Fig.6 | _ | 1.5 | pF |
| t _{rr} | reverse recovery time | when switched from $I_F = 10$ mA to $I_R = 10$ mA; $R_L = 100$ Ω ; measured at $I_R = 1$ mA; see Fig.7 | - | 4 | ns |
| V _{fr} | forward recovery voltage | when switched from $I_F = 10$ mA; $t_f = 20$ ns; see Fig.8 | _ | 1.75 | V |

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | CONDITIONS | VALUE | UNIT |
|----------------------|---|------------|-------|------|
| R _{th j-tp} | thermal resistance from junction to tie-point | | 200 | K/W |
| R _{th j-a} | thermal resistance from junction to ambient | note 1 | 315 | K/W |

Note

1. Device mounted on an FR4 printed-circuit board.

High-speed switching diode

BAS216

GRAPHICAL DATA

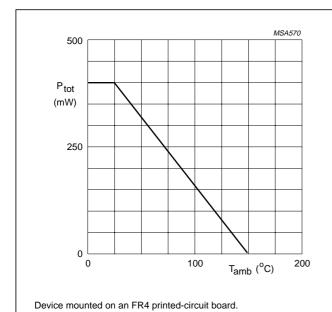
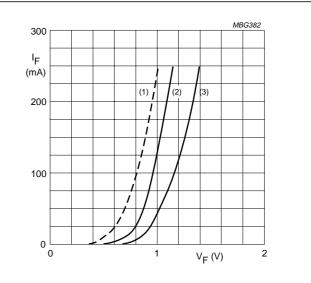


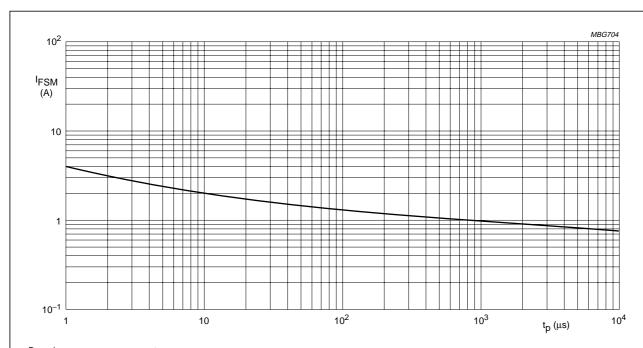
Fig.2 Maximum permissible total power dissipation as a function of ambient

temperature.



- (1) $T_i = 150 \,^{\circ}\text{C}$; typical values.
- (2) $T_j = 25$ °C; typical values.
- (3) T_j = 25 °C; maximum values.

Fig.3 Forward current as a function of forward voltage.



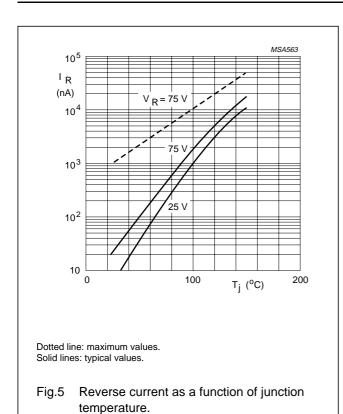
Based on square wave currents.

 T_j = 25 °C prior to surge.

Fig.4 Maximum permissible non-repetitive peak forward current as a function of pulse duration.

High-speed switching diode

BAS216



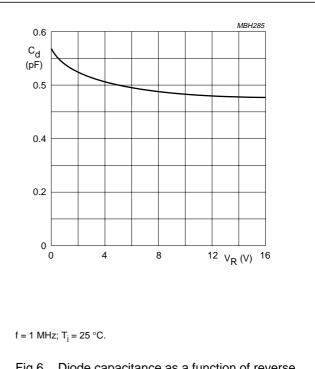


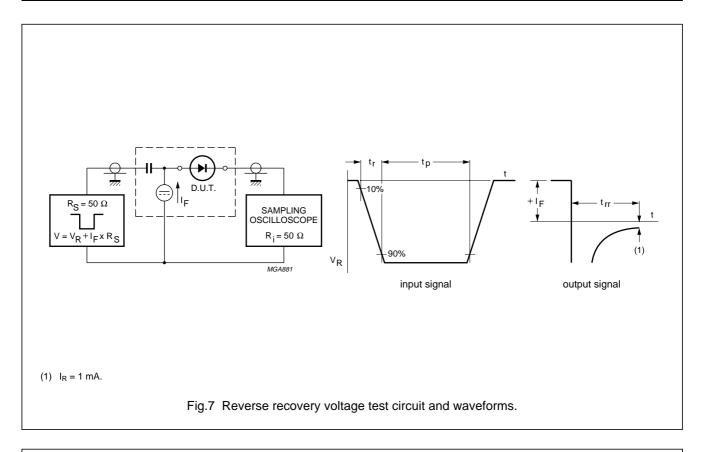
Fig.6 Diode capacitance as a function of reverse voltage; typical values.

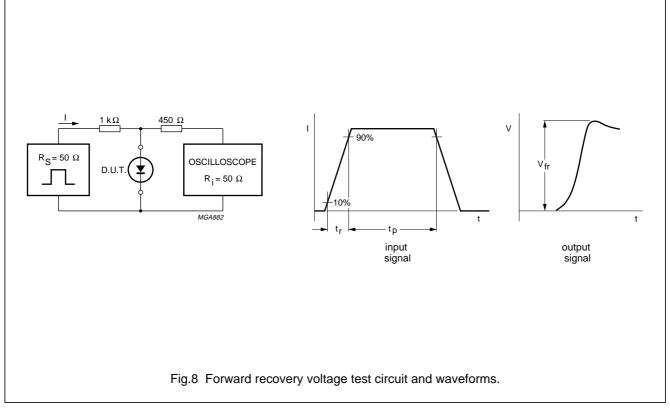
2002 May 28

5

High-speed switching diode

BAS216





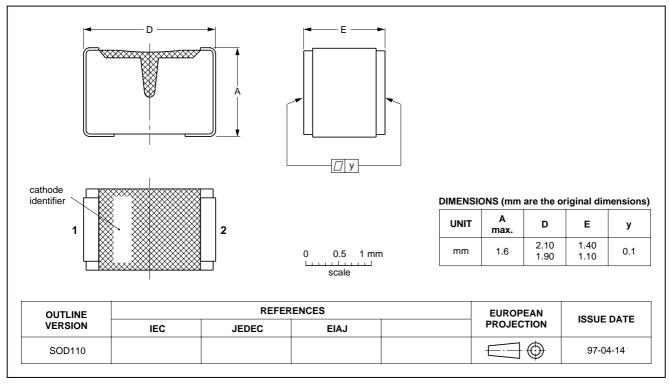
High-speed switching diode

BAS216

PACKAGE OUTLINE

Very small ceramic rectangular surface mounted package

SOD110



High-speed switching diode

BAS216

DATA SHEET STATUS

| DATA SHEET STATUS(1) | PRODUCT STATUS ⁽²⁾ | DEFINITIONS |
|----------------------|----------------------------------|--|
| Objective data | Development | This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice. |
| Preliminary data | Qualification | This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product. |
| Product data | Production | This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Changes will be communicated according to the Customer Product/Process Change Notification (CPCN) procedure SNW-SQ-650A. |

Notes

- 1. Please consult the most recently issued data sheet before initiating or completing a design.
- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.

DEFINITIONS

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information — Applications that are described herein for any of these products are for illustrative purposes only. Philips Semiconductors make no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

DISCLAIMERS

Life support applications — These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips Semiconductors customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips Semiconductors for any damages resulting from such application.

Right to make changes — Philips Semiconductors reserves the right to make changes, without notice, in the products, including circuits, standard cells, and/or software, described or contained herein in order to improve design and/or performance. Philips Semiconductors assumes no responsibility or liability for the use of any of these products, conveys no licence or title under any patent, copyright, or mask work right to these products, and makes no representations or warranties that these products are free from patent, copyright, or mask work right infringement, unless otherwise specified.

High-speed switching diode

BAS216

NOTES

High-speed switching diode

BAS216

NOTES

High-speed switching diode

BAS216

NOTES

Philips Semiconductors – a worldwide company

Contact information

For additional information please visit http://www.semiconductors.philips.com. Fax: +31 40 27 24825 For sales offices addresses send e-mail to: sales.addresses@www.semiconductors.philips.com.

© Koninklijke Philips Electronics N.V. 2002

SCA74

All rights are reserved. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner.

The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice. No liability will be accepted by the publisher for any consequence of its use. Publication thereof does not convey nor imply any license under patent- or other industrial or intellectual property rights.

Printed in The Netherlands

613514/05/pp12

Date of release: 2002 May 28

Document order number: 9397 750 09729

Let's make things better.

Philips Semiconductors



